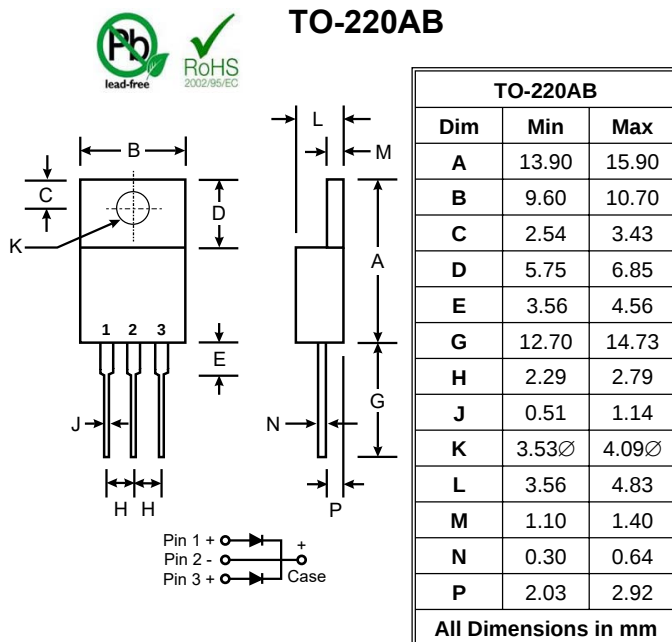


Features

- Schottky Barrier Chip
- Ideally Suited for Automatic Assembly
- Low Power Loss, High Efficiency
- For Use in Low Voltage Application
- Guard Ring Die Construction
- Plastic Case Material has UL Flammability Classification Rating 94V-O

Mechanical Data

- Case: TO-220AB, Molded Plastic
- Terminals: Plated Leads Solderable per MIL-STD-202, Method 208
- Polarity: See Diagram
- Mounting Position: Any
- **Lead Free: For RoHS / Lead Free Version**



Maximum Ratings and Electrical Characteristics @T_A=25°C unless otherwise specified

Single Phase, half wave, 60Hz, resistive or inductive load.

For capacitive load, derate current by 20%.

Characteristic	Symbol	MBR 3040 CT	MBR 3045 CT	MBR 3050 CT	MBR 3060 CT	MBR 30100 CT	MBR 30150 CT	MBR 30200 CT	Unit
Peak Repetitive Reverse Voltage	V _{RRM}	40	45	50	60	100	150	200	V
Working Peak Reverse Voltage	V _{RWM}								
DC Blocking Voltage	V _R								
RMS Reverse Voltage	V _{R(RMS)}	28	31	35	42	70	105	140	V
Average Rectified Output Current @T _L = 75°C (Note 1)	I _O	30.0							A
Non-Repetitive Peak Forward Surge Current 8.3ms Single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	200							A
Forward Voltage @I _F = 15A	V _{FM}	0.70		0.80		0.85		0.92	V
Peak Reverse Current @T _A = 25°C At Rated DC Blocking Voltage @T _A = 100°C	I _{RM}	0.1 20							mA
Typical Junction Capacitance (Note 2)	C _j	350		280		200			pF
Typical Thermal Resistance (Note 1)	R _{θJA}	3.0				2.0			°C/W
Operating and Storage Temperature Range	T _j , T _{STG}	-55 to +150						-55 to +175	°C

Note: 1. Valid provided that leads are kept at ambient temperature at a distance of 9.5mm from the case.

2. Measured at 1.0 MHz and applied reverse voltage of 4.0V D.C.

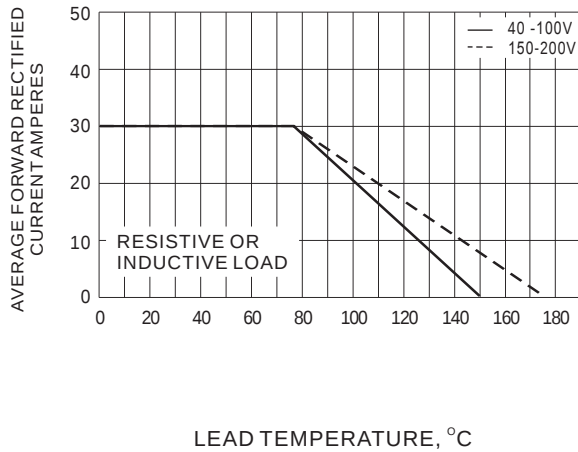


Fig.1- FORWARD CURRENT DERATING CURVE

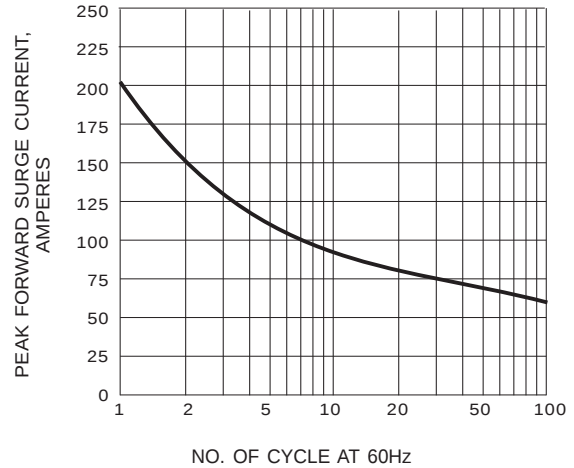


Fig.2- MAXIMUM NON-REPETITIVE SURGE CURRENT

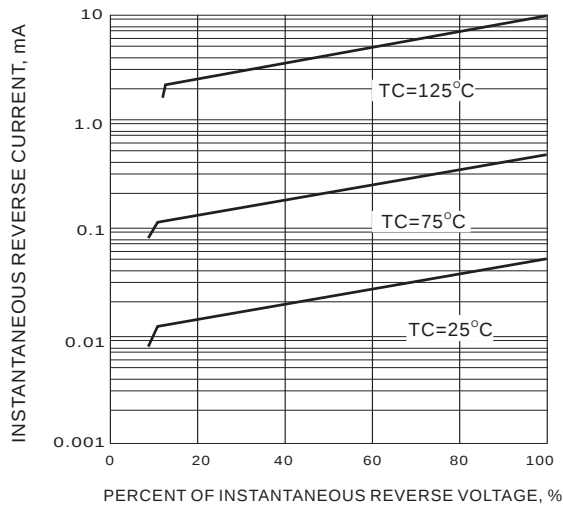


Fig.3- TYPICAL REVERSE CHARACTERISTIC

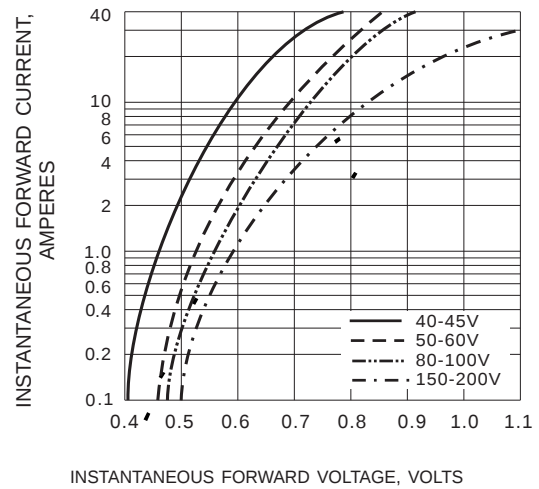


Fig.4- TYPICAL INSTANTANEOUS FORWARD CHARACTERISTIC